

### General Description

The SDC211 is a chip that is composed of Hall sensor and output coil drivers, it's applied to two phase DC motor. The high sensitivity of Hall effect sensor is suitable for motors from mini-type CPU coolers to DC fans. Typical operation current is 250mA and operating voltage range is wide. FG signal provides a square waveform output for the detection of the motor speed.

### Features

- Built-in Hall sensor/drivers
- Wide operating voltage range: 4.0V~20V
- Output sink current up to 250mA
- Low quiescent supply current under 5mA
- Built-in FG output
- Package: TO-94

### Applications

- Dual coils brushless DC motor
- Dual coils brushless DC fan
- Revolution counting
- Speed measurement

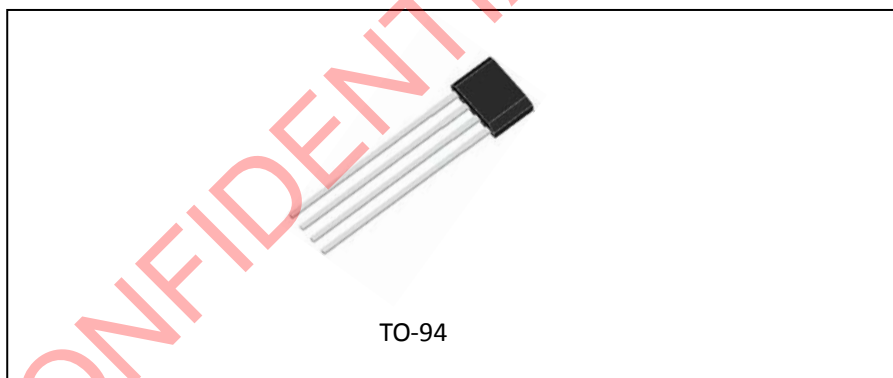


Figure 1. Package Type

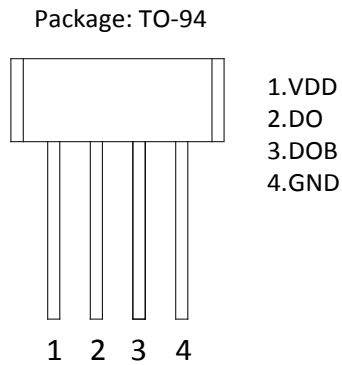
**Pin Configuration**


Figure 2. Pin Configuration

Pin Number	Pin Name	Function
1	FG	Rotation speed output (O.C)
2	DO/VCC	Coil driver output/Power input
3	DOB/VCC	Coil driver output/Power input
4	GND	IC ground

Table1. Pin Description

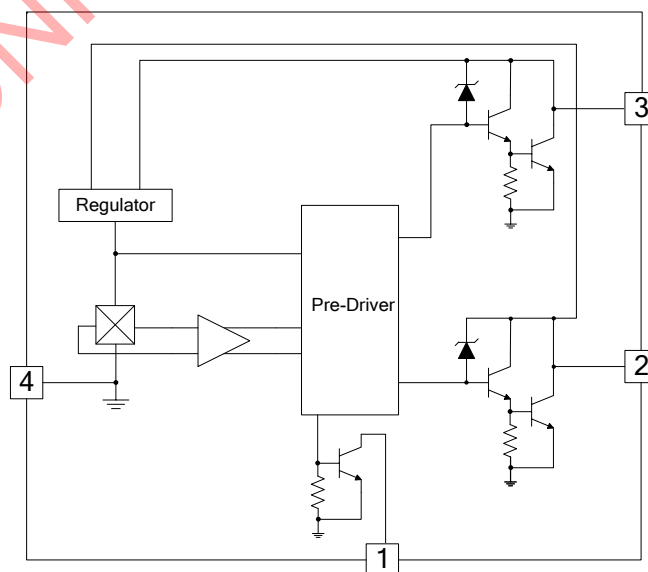
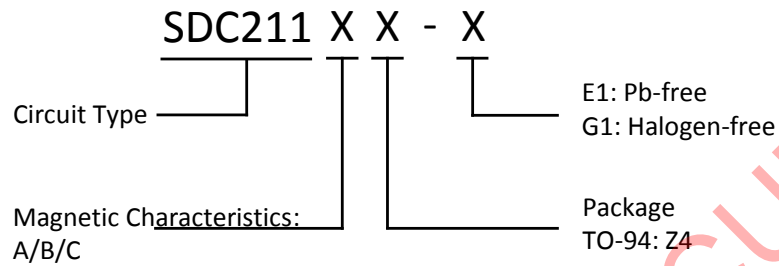
**Functional Block Diagram**


Figure 3. Functional Block Diagram

**Ordering Information**


Package	Temperature Range	Part Number		Marking ID		Packing Type
		Pb-free	Halogen-free	Pb-free	Halogen-free	
TO-94	-20°C~85°C	SDC211AZ4-E1	SDC211AZ4-G1	211	211G	Bulk
		SDC211BZ4-E1	SDC211BZ4-G1	211	211G	Bulk
		SDC211CZ4-E1	SDC211CZ4-G1	211	211G	Bulk

**Absolute Maximum Ratings** (Note: Stresses greater than those listed under absolute maximum ratings may cause permanent damage to the device.)

Parameter		Symbol	Value	Units
Supply Voltage		$V_{CC}$	24	V
Output Voltage		$V_{OUT}$	24	V
Magnetic flux density		B	unlimited	GS
Output current	Continuous	$I_{out}$	250	mA
	Hold		400	
	Peak		700	
Storage temperature range		$T_S$	-65~150	°C
Package power dissipation		$P_D$	550	mW
ESD, HBM model per Mil-Std-883, Method 3015		HBM	2000	V
ESD, MM model per JEDEC EIA/JESD22-A115		MM	200	V
Latch-up test per JEDEC 78		-	200	mA
Maximum junction temperature		$T_J$	150	°C

Table 2. Absolute Maximum Ratings

**Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
Power supply	$V_{CC}$	4.0	20	V
Operation temperature	$T_a$	-20	85	°C

Table 3. Recommended Operating Conditions

**Electrical Characteristics** ( $T_a=25^\circ\text{C}$ ,  $V_{CC}=12\text{V}$ , unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating voltage	$V_{CC}$	-	4.0	12	20	V
Quiescent supply current	$I_{CC}$	$V_{CC}=20\text{V}, B>150\text{GS}, V_{DOB}=V_{CC}$ (or $B<-150\text{GS}, V_{DO}=V_{CC}$ )	-	2.5	7.0	mA
DO/DOB saturation voltage	$V_{SAT}$	$B>150\text{GS}, V_{DOB}=V_{CC}, I_{DO}=200\text{mA}$ (or $B<-150\text{GS}, V_{DO}=V_{CC}, I_{DOB}=200\text{mA}$ )	-	-	1.2	V
FG leakage current	$I_{OFF}$	$B>150\text{GS}, V_{DOB}=V_{CC}, V_{FG}=20\text{V}$	-	-	1	uA
FG saturation voltage	$V_{FG}$	$B<-150\text{GS}, V_{DO}=V_{CC}, I_{FG}=5\text{mA}$	-	0.2	0.5	V
Rise time	$t_r$	$R_L=820\Omega, C_L=20\text{pF}$	-	0.5	10	us
Fall time	$t_f$	$R_L=820\Omega, C_L=20\text{pF}$	-	0.5	1.5	us
Switch time	$\Delta t$	$R_L=820\Omega, C_L=20\text{pF}$	-	0.5	1.0	us

Table 4. Electrical Characteristics

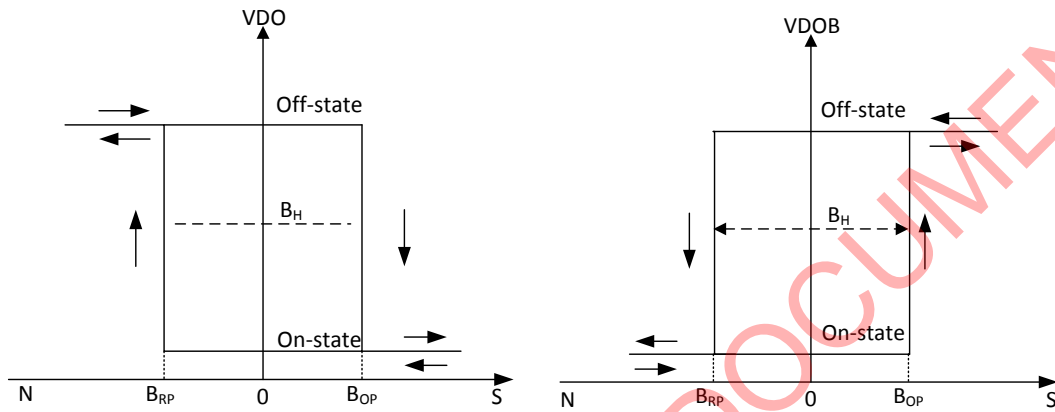
**Magnetic Characteristics** (Ta=25°C, V<sub>CC</sub>=12V, unless otherwise specified)


Figure 4. Magnetic Characteristics

**Grade A**

Parameter	Symbol	Min	Max	Unit
Operate point	B <sub>OP</sub>	10	50	GS
Release point	B <sub>RP</sub>	-50	-10	GS

**Grade B**

Parameter	Symbol	Min	Max	Unit
Operate point	B <sub>OP</sub>	-	70	GS
Release point	B <sub>RP</sub>	-70	-	GS

**Grade C**

Parameter	Symbol	Min	Max	Unit
Operate point	B <sub>OP</sub>	-	90	GS
Release point	B <sub>RP</sub>	-90	-	GS

Table 5. Magnetic Characteristics

Note: when south pole of magnetic is faced to the marked side of IC, the magnetic field is positive.

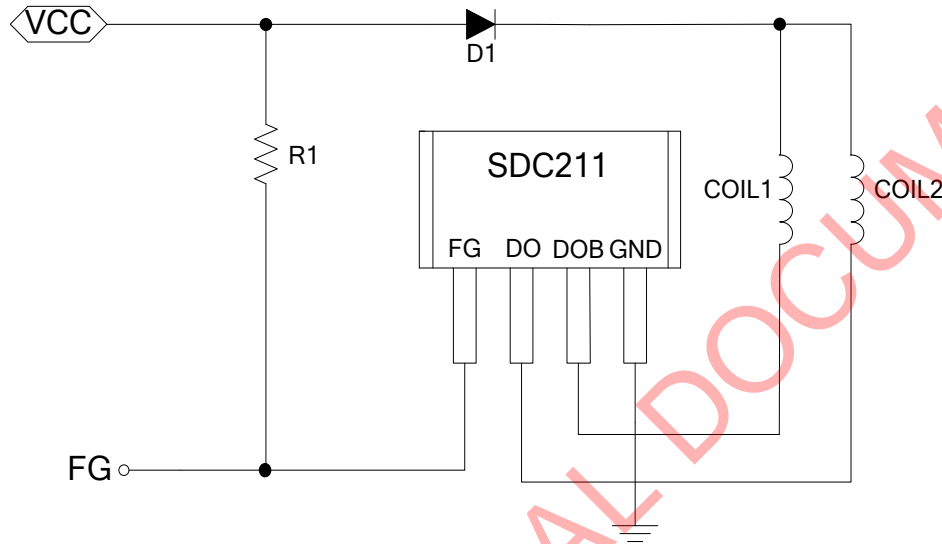
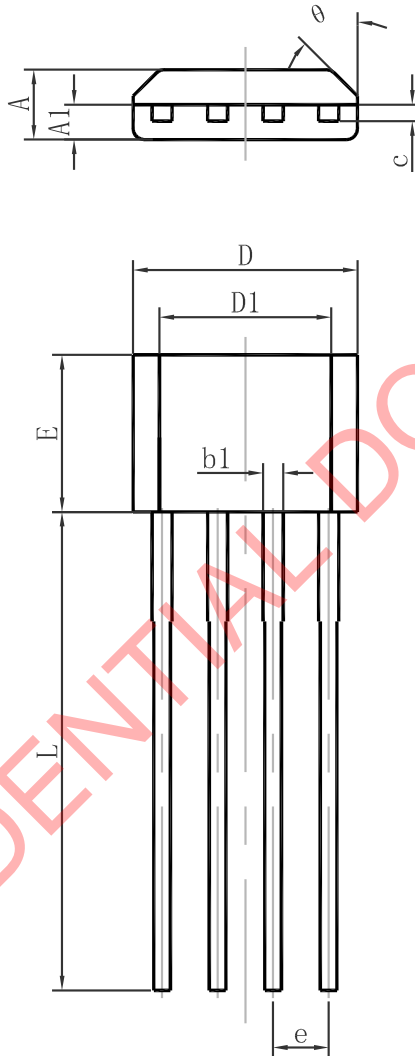
**Typical Application**


Figure 5. Typical Application

**Package Dimension**
**TO-94**


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.800	0.055	0.071
A1	0.700	0.900	0.028	0.035
b1	0.380	0.550	0.015	0.022
C	0.360	0.510	0.014	0.020
D	5.050	5.350	0.202	0.214
D1	4.550	4.850	0.128	0.194
E	3.450	3.750	0.136	0.148
e	1.270 TYP.		0.050 TYP.	
L	14.300	14.700	0.572	0.588
θ	10°TYP.		10°TYP.	



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